





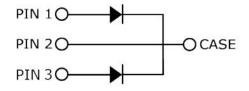
# S5D40120D 1200V SIC POWER SCHOTTKY RECTIFIER



#### **Description**

S5D40120D is a single SiC Schottky rectifier packaged in TO-247AD(TO-247-3) case. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S5D40120D is ideal for energy sensitive, high frequency applications in challenging environments.

#### **Circuit Diagram**



#### **Features**

- 175°C T<sub>J</sub> operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

#### **Applications**

- · Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	1200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=150°C, rectangular wave form	20 (per leg) 40 (per device)	Α
Peak One Cycle Non-Repetitive Surge Current (per leg)	I <sub>FSM</sub>	10ms, Half Sine pulse, T <sub>J</sub> = 25 °C	145	Α
Non-repetitive Peak Forward Surge Current (per leg)	I <sub>F, MAX</sub>	10 us, Half Sine pulse , T <sub>J</sub> =25°C	1575	Α

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#### **Electrical Characteristics:**

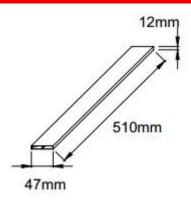
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (per leg)*	V <sub>F1</sub> @ 20A, Pulse, T <sub>J</sub> = 25 °C		1.5	1.8	V
	$V_{F2}$	@ 20A, Pulse, T <sub>J</sub> = 175 °C	2.2	3.0	V
Reverse Current (per leg)*	$I_{R1}$		2	25	uA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 175  ^{\circ}\text{C}$	10	150	uA
Junction Capacitance(per leg)	Ст	VR=0V, Tj=25℃, f=1MHz	1620	-	pF

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

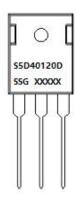
#### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to	R <sub>0</sub> JC	DC operation, Tj=25°C	0.84(per leg)	°C/W
Case		-	0.42(both leg)	C/VV

# **Tube Specification**



#### **Marking Diagram**



Where XXXXX is YYWWL

 S5D
 = Device Type

 D
 = Package type

 40
 = Forward Current (40A)

 120
 = Reverse Voltage (1200V)

 SSG
 SSG

 YY
 = Year

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

#### **Ordering Information**

Device	Package	Shipping
S5D40120D	TO-247AD(TO-247-3)	25pcs /tube

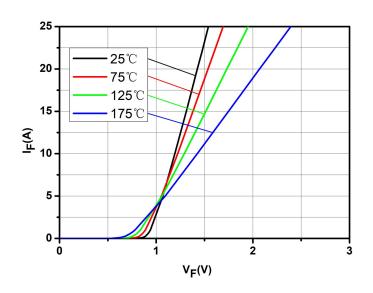
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## **Ratings and Characteristics Curves (per leg)**



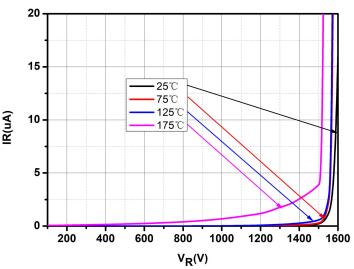


Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics

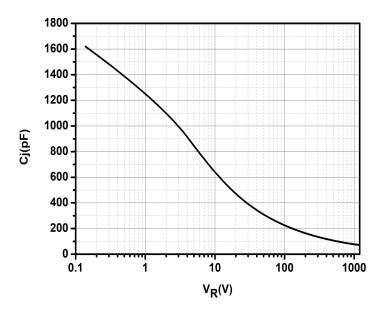


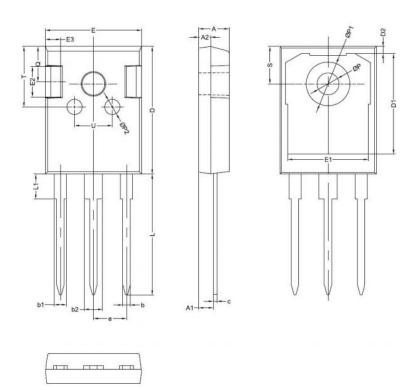
Fig.3-Capacitance vs. Reverse Voltage







## **Mechanical Dimensions TO-247AD**



SYMBOL	Millimeters				
	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.40		
b1	1.80	2.00	2.20		
b2	2.80	3.00	3.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.55			
D2		1.20			
E	15.45	15.80	16.00		
E1		13.30	14.114.1		
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.70		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1		7.40		
P2		2.50			
Q		5.80			
S	6.05	6.15	6.25		
T		10.00			
U		6.20	Î		







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